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DECLARATION

As a below named inventor, I hereby declare that:

My residence, post office address and citizenship are as stated below next to my name.

I believe I am the original, first and sole inventor (if only one name is listed below) or the below named inventors are the original, first and joint inventors (if plural names are listed below) of the subject matter which is claimed and for which a patent is sought on the invention entitled METHOD OF FABRICATING COPPER-BASED SEMICONDUCTOR DEVICES USING A SACRIFICIAL DIELECTRIC LAYER, the Specification of which:

	is attached hereto. was filed on	as Application S	Serial No	
I hereb including the cla		eviewed and underst	and the contents of the	above-identified specification,
material to pate				information known to me to be teriality" is defined in Title 37,
patent, United S any foreign appl	tates provisional appl	cation(s), or inventor ited States provisional	's certificate listed below	of any foreign application(s) for and have also identified below 's certificate having a filing date
PRIORITY APPLICATION(S)			Priority Claimed	
(Number)	(Coun	try)	(Date Filed)	Yes/No
(Number)	(Coun	try)	(Date Filed)	Yes/No
isted below and United States ap acknowledge the claimed in this	, insofar as the subject oplication in the manner of duty to disclose all application, as "mate	ct matter of each of the ner provided by the f information known to riality" is defined in	ne claims of this applications paragraph of Title 3 me to be material to portific Title 37, Code of Federal Processing Pr	any United States application(s) tion is not disclosed in the prior 35, United States Code, § 112, I atentability of the subject matter eral Regulations, § 1.56, which r PCT international filing date of
(Applie	cation Serial No.)	(Filing Date)	(Status)	
(Applie	cation Serial No.)	(Filing Date)	(Status)	
I hereb	v direct that all corr	espondence and teler	shone calls be addresse	d to Randall C. Furlong, Ph.D.

Williams, Morgan & Amerson, P.C., 7676 Hillmont, Suite 250, Houston, Texas 77040, (713) 934-4061.

I HEREBY DECLARE THAT ALL STATEMENTS MADE OF MY OWN KNOWLEDGE ARE TRUE AND THAT ALL STATEMENTS MADE ON INFORMATION AND BELIEF ARE BELIEVED TO BE TRUE; AND FURTHER THAT THESE STATEMENTS WERE MADE WITH THE KNOWLEDGE THAT WILLFUL FALSE STATEMENTS AND THE LIKE SO MADE ARE PUNISHABLE BY FINE OR IMPRISONMENT, OR BOTH, UNDER SECTION 1001 OF TITLE 18 OF THE UNITED STATES CODE AND THAT SUCH WILLFUL FALSE STATEMENTS MAY JEOPARDIZE THE VALIDITY OF THE APPLICATION OR ANY PATENT ISSUED THEREON.

Inventor's Full Name:	STEPHEN KEETAI PARK			
Inventor's Signature:	Stew Pull	· ?		
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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of:

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STEPHEN KEETAI PARK

\$ Examiner: Unknown

Serial No.: Unknown § Group Art Unit: Unknown §

Filed: Concurrently Herewith § Atty Docket: 2000.029900/TT3586

For: METHOD OF FABRICATING COPPER-BASED §

METHOD OF FABRICATING COPPER-BASED

SEMICONDUCTOR DEVICES USING A

SACRIFICIAL DIELECTRIC LAYER

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POWER OF ATTORNEY

Assistant Commissioner for Patents

Washington, D.C. 20231

Sir:

The undersigned, being the inventor named in the above-identified application, hereby revokes any previous Powers of Attorney and appoints:

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as its attorney or agent so long as they remain with such firms, with full power of substitution and revocation, to prosecute the application, to make alterations and amendments therein, to transact all business in the Patent and Trademark Office in connection therewith, and to receive any Letters Patent, and for one year after issuance of such Letters Patent to file any request for a certificate of correction that may be deemed appropriate.

Please direct all communications as follows:

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Signature:	Atem 6	Full	Date:	1/	18	100	
	Stephen Keetai Park						